



## TPD4E001-Q1 4-Channel ESD Protection Array With 1.5-pF I/O Capacitance

### 1 Features

- AEC-Q100 Qualified With the Following Results:
  - Device Temperature Grade 1: –40°C to 125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level 3B
  - HBM Level 15 kV
  - Device CDM ESD Classification Level C5
- IEC 61000-4-2 Level 4 ESD Protection
  - ±8-kV Contact Discharge
  - ±15-kV Air-Gap Discharge
- IEC 61000-4-5 Surge Protection
  - 5.5 A (8/20 μs)
- Low 1.5-pF Input Capacitance
- Low 10-nA Maximum Leakage Current
- 0.9-V to 5.5-V Supply Voltage Range

### 2 Applications

- End Equipment
  - Automotive Head Unit
  - Automotive Rear Seat Entertainment
  - Automotive Rear Camera Systems
- Interfaces
  - USB 2.0
  - Ethernet
  - Precision Analog Interfaces

### 3 Description

The TPD4E001-Q1 device is a low-capacitance TVS diode array designed for ESD protection in sensitive electronics connected to communication lines. Each channel consists of a pair of transient-voltage-suppression diodes that steer ESD pulses to  $V_{CC}$  or GND. The TPD4E001-Q1 protects against ESD events up to ±8-kV contact discharge and ±15-kV air-gap discharge, as specified in IEC 61000-4-2 international standard. This device has a low capacitance of 1.5-pF per channel making it ideal for use in high-speed data interfaces. The low leakage current (10 nA maximum) ensures minimum power consumption for the system and high accuracy for analog interfaces.

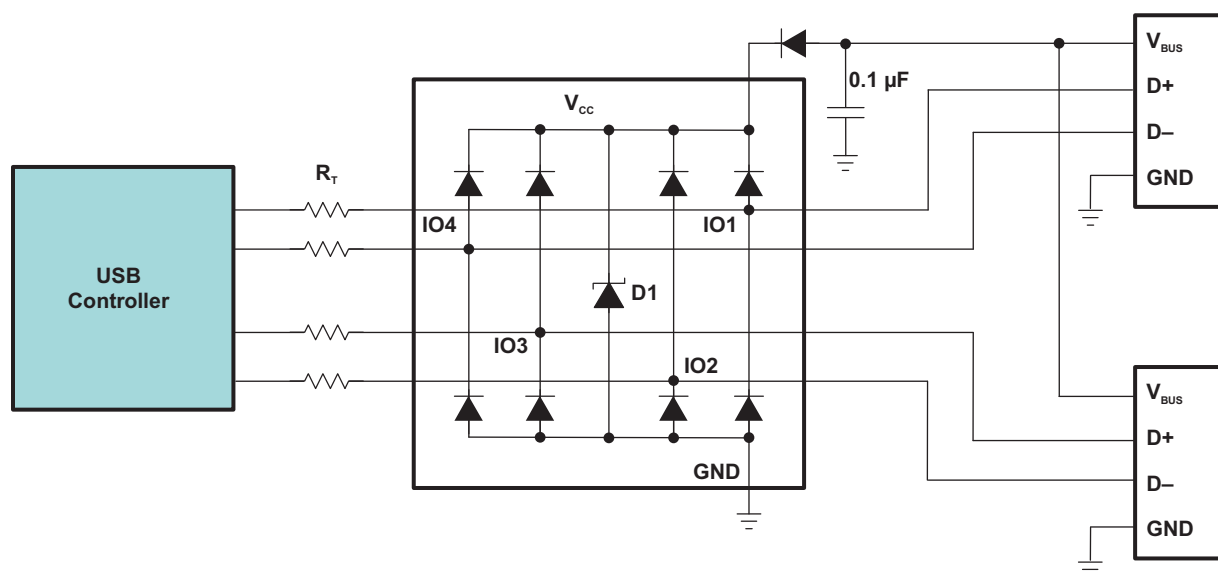
Additionally, this device is ideal for protecting automotive head units, automotive rear seat entertainment, and automotive rear camera systems that use USB 2.0, Ethernet, or precision analog interfaces.

#### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)   |
|-------------|------------|-------------------|
| TPD4E001-Q1 | SOT-23 (6) | 2.90 mm × 1.60 mm |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

#### Typical Schematic



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

### Changes from Revision C (June 2013) to Revision D Page

- Added *Pin Configuration and Functions* section, *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section ..... **1**
- Changed Device CDM ESD Classification Level from C4B to C5 ..... **1**

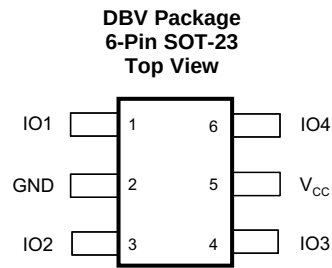
### Changes from Revision B (February 2012) to Revision C Page

- Changed maximum  $I_{CC}$  supply current in Electrical Characteristics..... **4**

### Changes from Revision A (April 2013) to Revision B Page

- Revised text in DESCRIPTION section..... **1**
- Revised [Figure 2](#) graph ..... **4**
- Revised APPLICATION INFORMATION schematic ..... **7**

## 5 Pin Configuration and Functions



### Pin Functions

| PIN             |     | TYPE | DESCRIPTION                                                                        |
|-----------------|-----|------|------------------------------------------------------------------------------------|
| NAME            | NO. |      |                                                                                    |
| GND             | 2   | GND  | Ground                                                                             |
| IO1             | 1   | I/O  | ESD-protected channel                                                              |
| IO2             | 3   |      |                                                                                    |
| IO3             | 4   |      |                                                                                    |
| IO4             | 6   |      |                                                                                    |
| V <sub>CC</sub> | 5   | I    | Power-supply input. Bypass V <sub>CC</sub> to GND with a 0.1-μF ceramic capacitor. |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

|                                                                  | MIN  | MAX                   | UNIT |
|------------------------------------------------------------------|------|-----------------------|------|
| V <sub>CC</sub> Supply voltage                                   | −0.3 | 7                     | V    |
| V <sub>IO</sub> I/O voltage tolerance                            | −0.3 | V <sub>CC</sub> + 0.3 | V    |
| I <sub>PP</sub> Peak pulse current (Tp = 8/20 μs) <sup>(2)</sup> |      | 5.5                   | A    |
| P <sub>PP</sub> Peak pulse power (Tp = 8/20 μs) <sup>(2)</sup>   |      | 100                   | W    |
| T <sub>A</sub> Free air operating temperature                    | −40  | 125                   | °C   |
| T <sub>J</sub> Junction temperature                              |      | 150                   | °C   |
| T <sub>stg</sub> Storage temperature                             | −65  | 150                   | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Non-repetitive current pulse 8/20 μs exponentially decaying waveform according to IEC 61000-4-5.

### 6.2 ESD Ratings: AEC Q100

|                                            | VALUE                                                   | UNIT   |
|--------------------------------------------|---------------------------------------------------------|--------|
| V <sub>(ESD)</sub> Electrostatic discharge | Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup> | ±15000 |
|                                            | Charged-device model (CDM), per AEC Q100-011            | ±750   |

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 6.3 ESD Ratings: IEC 61000-4-2

|                                            | VALUE                           | UNIT   |
|--------------------------------------------|---------------------------------|--------|
| V <sub>(ESD)</sub> Electrostatic discharge | IEC 61000-4-2 contact discharge | ±8000  |
|                                            | IEC 61000-4-2 air-gap discharge | ±15000 |

## TPD4E001-Q1

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### 6.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                            |                                | MIN | NOM | MAX      | UNIT |
|----------------------------|--------------------------------|-----|-----|----------|------|
| $T_A$                      | Free air operating temperature | –40 |     | 125      | °C   |
| $V_{CC}$ pin               | Operating voltage              | 0.9 |     | 5.5      | V    |
| IO1, IO2,<br>IO3, IO4 pins | Operating voltage              | 0   |     | $V_{CC}$ | V    |

### 6.5 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPD4E001-Q1  | UNIT |
|-------------------------------|----------------------------------------------|--------------|------|
|                               |                                              | DBV (SOT-23) |      |
|                               |                                              | 6 PINS       |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 202.1        | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 146.2        | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 47.1         | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 37.6         | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 46.7         | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

### 6.6 Electrical Characteristics

 $V_{CC} = 5\text{ V} \pm 10\%$ , over operating free-air temperature range (unless otherwise noted)

| PARAMETER   | TEST CONDITIONS           |                                                                                                            | MIN  | TYP <sup>(1)</sup> | MAX      | UNIT |
|-------------|---------------------------|------------------------------------------------------------------------------------------------------------|------|--------------------|----------|------|
| $I_{CC}$    | Supply current            |                                                                                                            |      | 1                  | 200      | nA   |
| $V_F$       | Diode forward voltage     | $I_F = 10\text{ mA}$                                                                                       | 0.65 |                    | 0.95     | V    |
| $V_{BR}$    | Breakdown voltage         | $I_{BR} = 10\text{ mA}$                                                                                    | 11   |                    |          | V    |
| $V_{CLAMP}$ | Clamping voltage          | Surge strike <sup>(2)</sup> on IO pin, GND pin grounded, $V_{CC} = 5.5\text{ V}$ , $I_{PP} = 5.5\text{ A}$ |      | 16                 |          | V    |
| $V_{RWM}$   | Reverse standoff voltage  | IO pin to GND pin                                                                                          |      |                    | 5.5      | V    |
| $I_{IO}$    | Channel leakage current   | $V_{IO} = \text{GND to } V_{CC}$                                                                           |      |                    | $\pm 10$ | nA   |
| $C_{IO}$    | Channel input capacitance | $V_{CC} = 5\text{ V}$ , bias of $V_{CC}/2$ , $f = 10\text{ MHz}$                                           |      | 1.5                |          | pF   |

(1) Typical values are at  $V_{CC} = 5\text{ V}$  and  $T_A = 25^\circ\text{C}$ .

(2) Non-repetitive current pulse 8/20  $\mu\text{s}$  exponentially decaying waveform according to IEC 61000-4-5.

## 6.7 Typical Characteristics

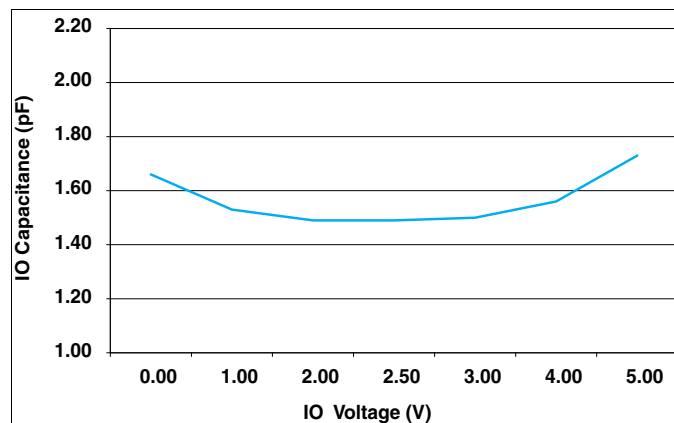


Figure 1. IO Capacitance versus IO Voltage ( $V_{CC} = 5\text{ V}$ )

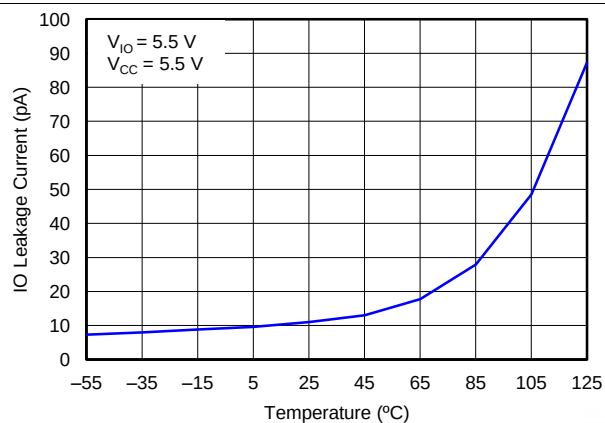


Figure 2. IO Leakage Current versus Temperature

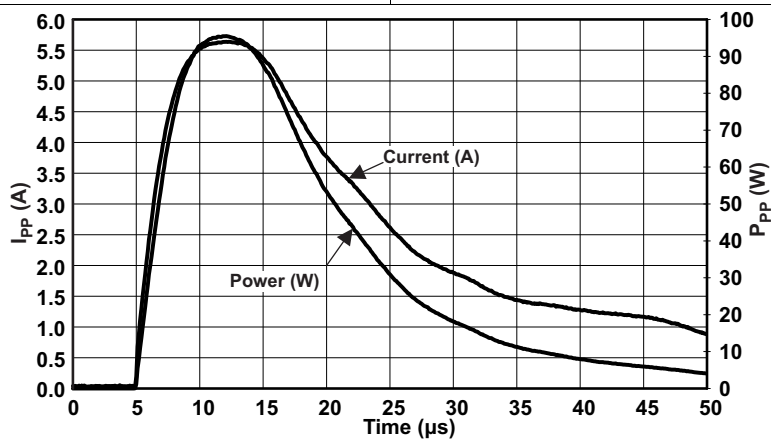


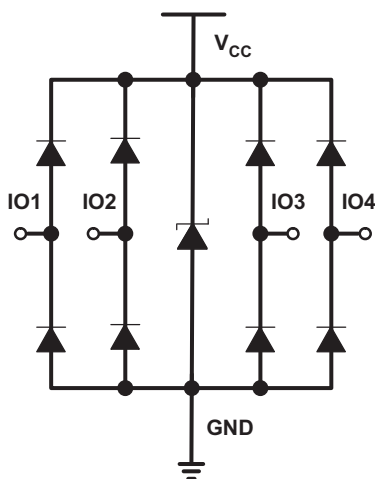
Figure 3. Peak Pulse Waveform,  $V_{CC} = 5.5\text{ V}$

## 7 Detailed Description

### 7.1 Overview

The TPD4E001-Q1 device is a low-capacitance, TVS diode array designed for ESD protection in sensitive electronics connected to communication lines. Each channel consists of a pair of transient voltage suppression diodes that steer ESD pulses to  $V_{CC}$  or GND. The TPD4E001-Q1 device protects against ESD events up to  $\pm 8$ -kV contact discharge and  $\pm 15$ -kV air-gap discharge, as specified in IEC 61000-4-2 international standard. This device has a low capacitance of 1.5-pF per channel making it ideal for use in high-speed data interfaces. The low-leakage current (10 nA max) ensures minimum power consumption for the system and high accuracy for analog interfaces.

### 7.2 Functional Block Diagram



### 7.3 Feature Description

#### 7.3.1 AEC-Q100 Qualified

This device is qualified according to the AEC-Q100 standard. The device temperature rating is Grade 1 ( $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ). The HBM Classification Level passed is 3B ( $> 8$  kV). The CDM Classification Level passed is C5 (all pins 750 V to  $< 1000$  V).

#### 7.3.2 IEC 61000-4-2 Level 4 ESD Protection

The device is specified at  $\pm 8$ -kV contact discharge and  $\pm 15$ -kV air gap discharge.

#### 7.3.3 IEC 61000-4-5 Surge Protection

This device is rated to pass at least 5.5-A of peak pulse current according to the IEC 61000-4-5 (8/20- $\mu\text{s}$  pulse) standard.

#### 7.3.4 Low 1.5-pF Input Capacitance

This device has a typical capacitance of 1.5-pF on each of the four IO pins. This allows for high speed signals on the IO pins in excess of 1 Gbps.

#### 7.3.5 Low 10-nA (Max) Leakage Current

This device is rated to have a maximum leakage current of 10-nA on each of the four IO pins.

#### 7.3.6 0.9-V to 5.5-V Supply Voltage Range

This device is specified to operate with a supply voltage (on  $V_{CC}$ ) between 0.9-V and 5.5-V to ensure sufficient signal integrity.

## 7.4 Device Functional Modes

The TPD4E001-Q1 device is a passive integrated circuit that triggers when voltages are above  $V_{BR}$  or below the lower diodes  $V_F$  ( $-0.6$  V). During ESD events, voltages as high as  $\pm 8$  kV (contact) can be directed to ground via the internal diode network. Once the voltages on the protected line fall below the trigger levels of TPD4E001-Q1 (usually within 10's of nano-seconds) the device reverts back to its high-impedance state.

## 8 Application and Implementation

### NOTE

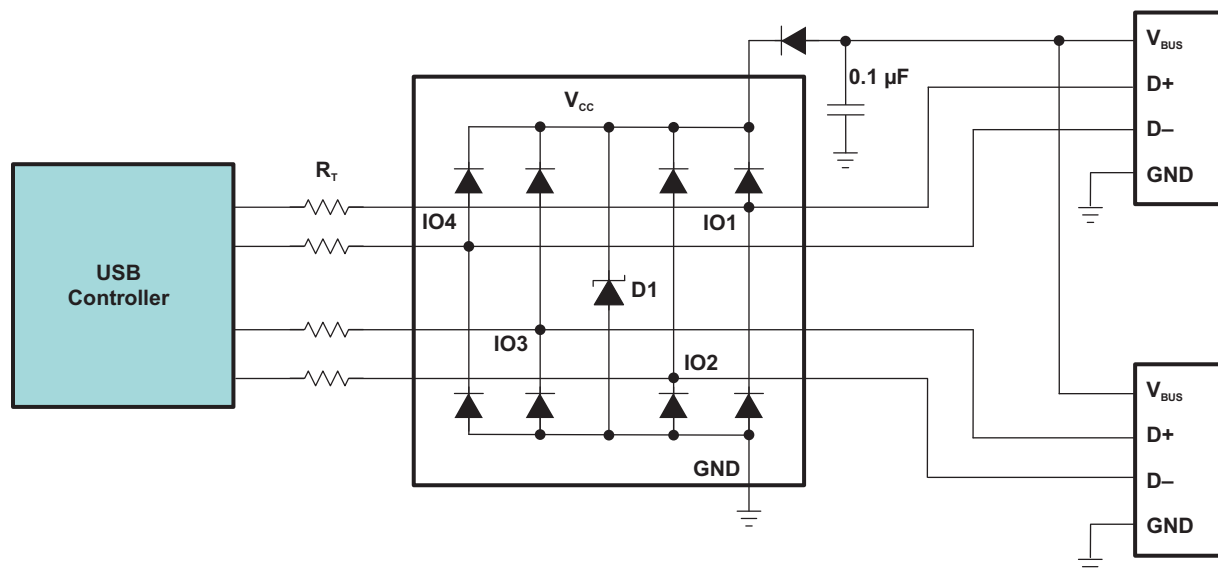
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The TPD4E001-Q1 device is a TVS diode array which is typically used to provide a path to ground for dissipating ESD events on high-speed signal lines between a human interface connector and a system. As the current from ESD passes through the TVS, only a small voltage drop is present across the diode. This is the voltage presented to the protected IC. The triggered TVS holds this voltage,  $V_{CLAMP}$ , to a safe level for the protected IC.

### 8.2 Typical Application

For this design example, one TPD4E001-Q1 device is being used in a dual USB 2.0 application. This will provide a complete port protection scheme.



**Figure 4. Typical Application Schematic**

## Typical Application (continued)

### 8.2.1 Design Requirements

For this design example, a single TPD4E001-Q1 device is used to protect all the pins on two USB2.0 connectors. Given the USB application, known parameters are listed in the [Table 1](#) table.

**Table 1. Design Parameters**

| DESIGN PARAMETER                             | VALUE         |
|----------------------------------------------|---------------|
| Signal range on IO1, IO2, IO3, or IO4        | 0 V to 3.6 V  |
| Voltage range on $V_{CC}$                    | 0 V to 5.25 V |
| Operating Frequency on IO1, IO2, IO3, or IO4 | 240 MHz       |

### 8.2.2 Detailed Design Procedure

To begin the design process, some parameters must be decided upon; the designer needs to know the following:

- Signal range on all protected lines
- Operating frequency on all protected lines

#### 8.2.2.1 Signal Range on IO1 Through IO4

The TPD4E001-Q1 device has 4 identical protection channels for signal lines. The symmetry of the device provides flexibility when selecting which of the 4 IO channels will protect which signal lines. Any IO will support a signal range of 0 to  $(V_{CC} + 0.3)$  V. Therefore, this device will support the USB 2.0 signal swing assuming  $V_{CC}$  is set appropriately.

#### 8.2.2.2 Voltage Range on $V_{CC}$

The  $V_{CC}$  pin can be connected in one of two ways:

- If the  $V_{CC}$  pin connects to the system power supply, the TPD4E001-Q1 device works as a transient suppressor for any signal swing above  $V_{CC} + V_F$ . TI recommends a 0.1- $\mu$ F capacitor on the device  $V_{CC}$  pin for ESD bypass.
- If the  $V_{CC}$  pin does not connect to the system power supply, the TPD4E001-Q1 device can tolerate higher signal swing in the range up to 10 V. Note that TI still recommends a 0.1- $\mu$ F capacitor at the  $V_{CC}$  pin for ESD bypass.

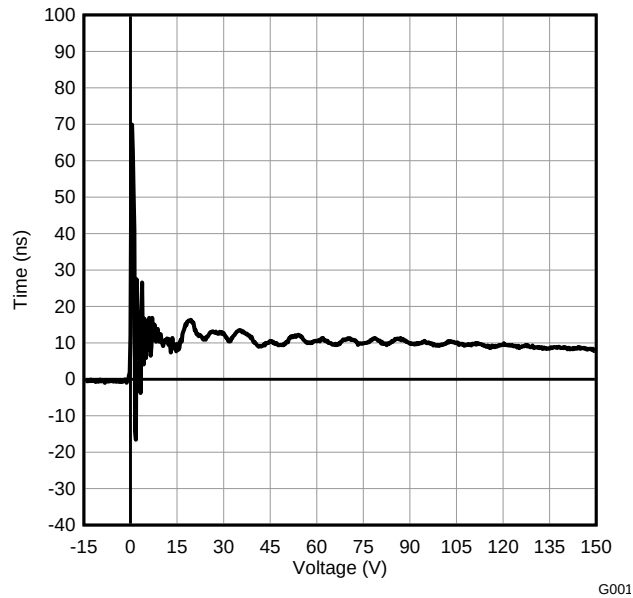
If this pin is connected to the USB 2.0  $V_{BUS}$  supply or left floating, the allowable signal swing is enough for a USB 2.0 application.

#### 8.2.2.3 Bandwidth on IO1 Through IO4

Each IO pin on the TPD4E001-Q1 device has a typical capacitance of 1.5 pF. This capacitance is low enough to easily support USB 2.0 data rates.



### 8.2.3 Application Curve



**Figure 5. IEC 61000-4-2 Voltage Clamp Waveform +8kV Contact**

## 9 Power Supply Recommendations

This device is a passive ESD protection device so there is no need to power it. Do not violate the maximum voltage specifications for each pin.

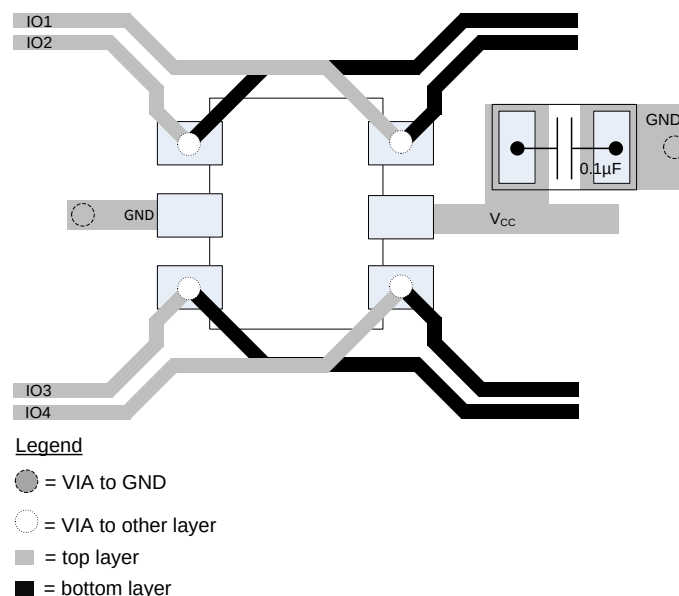
## 10 Layout

### 10.1 Layout Guidelines

When placed near the connector, the TPD4E001-Q1 device's ESD solution offers little or no signal distortion during normal operation due to low IO capacitance and ultra-low leakage-current specifications. The TPD4E001-Q1 device ensures that the core circuitry is protected and the system is functioning properly in the event of an ESD strike. For proper operation, observe the following layout and design guidelines:

- Place the TPD4E001-Q1 device close to the connector. This allows the device to take away the energy associated with ESD strike before it reaches the internal circuitry of the system board.
- Place a 0.1- $\mu$ F capacitor very close to the  $V_{CC}$  pin. This limits any momentary voltage surge at the IO pin during the ESD strike event.
- Ensure that there is enough metallization for the  $V_{CC}$  and GND loop. During normal operation, the TPD4E001-Q1 device consumes nA leakage current. But during the ESD event,  $V_{CC}$  and GND may see 15 A to 30 A of current, depending on the ESD level. Sufficient current path enables safe discharge of all the energy associated with the ESD strike.
- Leave the unused IO pins floating.
- One can connect the  $V_{CC}$  pin in two different ways:
  - a. If the  $V_{CC}$  pin connects to the system power supply, the TPD4E001-Q1 works as a transient suppressor for any signal swing above  $V_{CC} + V_F$ . TI recommends a 0.1- $\mu$ F capacitor on the device  $V_{CC}$  pin for ESD bypass.
  - b. If the  $V_{CC}$  pin does not connect to the system power supply, the TPD4E001-Q1 can tolerate higher signal swing in the range up to 10 V. Note that TI still recommends a 0.1- $\mu$ F capacitor at the  $V_{CC}$  pin for ESD bypass.
- The optimum placement is as close to the connector as possible.
  - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
  - The PCB designer needs to minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
  - Electric fields tend to build up on corners, increasing EMI coupling.

### 10.2 Layout Example



## 11 Device and Documentation Support

### 11.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 11.2 Trademarks

E2E is a trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 11.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 11.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPD4E001QDBVRQ1  | ACTIVE        | SOT-23       | DBV                | 6    | 3000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | AAXQ                    | <a href="#">Samples</a> |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

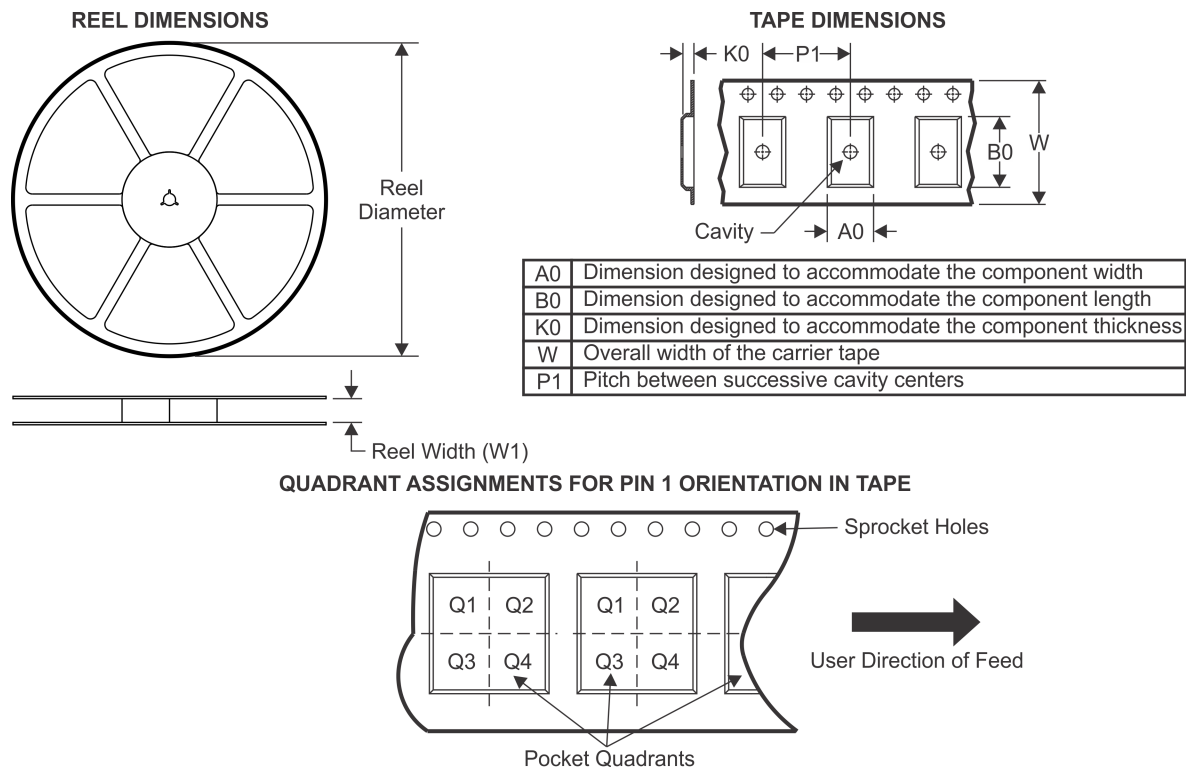
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPD4E001-Q1 :**

- Catalog: [TPD4E001](#)

**NOTE:** Qualified Version Definitions:

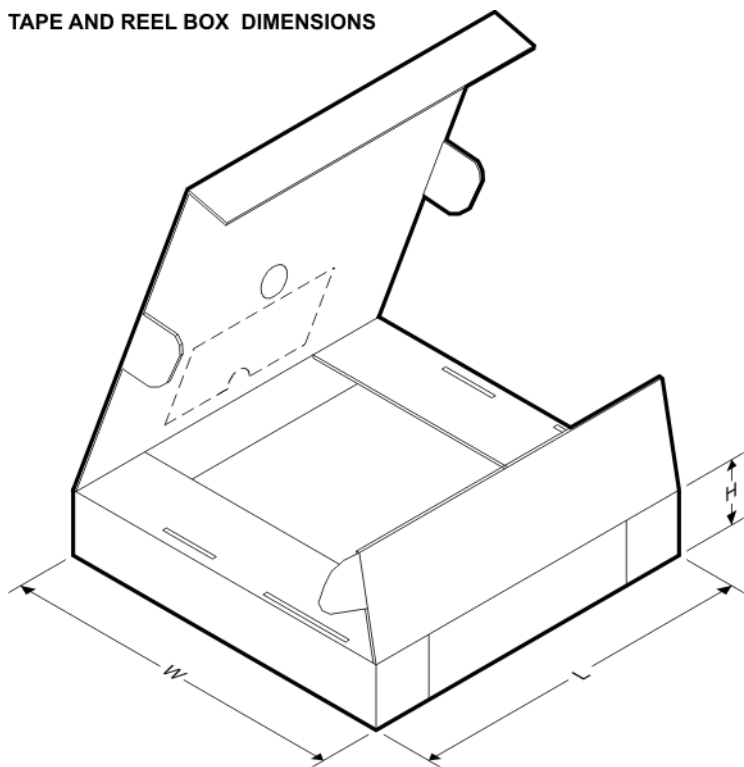
- Catalog - TI's standard catalog product

**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPD4E001QDBVRQ1 | SOT-23       | DBV             | 6    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |

## TAPE AND REEL BOX DIMENSIONS

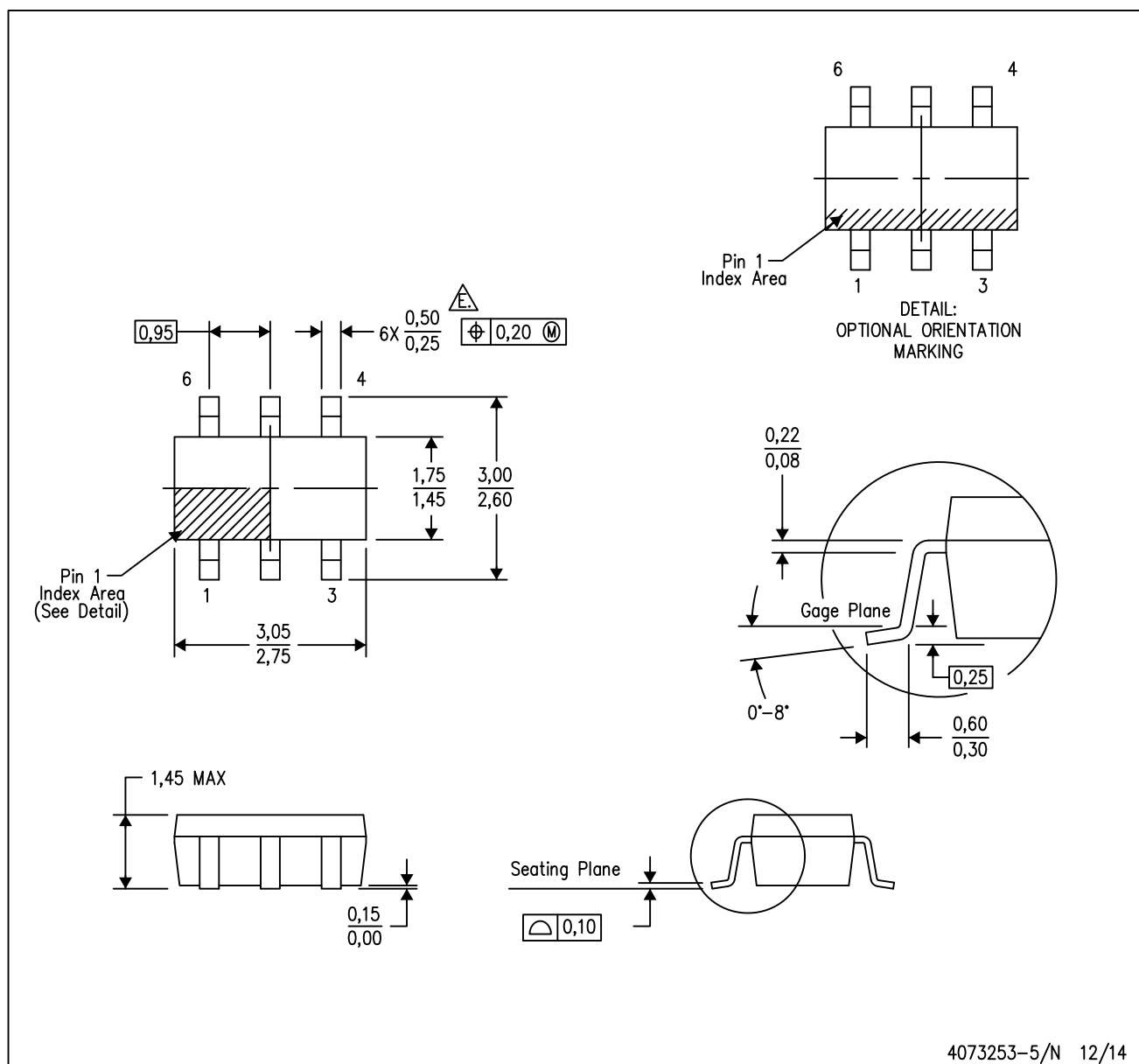


\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPD4E001QDBVRQ1 | SOT-23       | DBV             | 6    | 3000 | 180.0       | 180.0      | 18.0        |

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



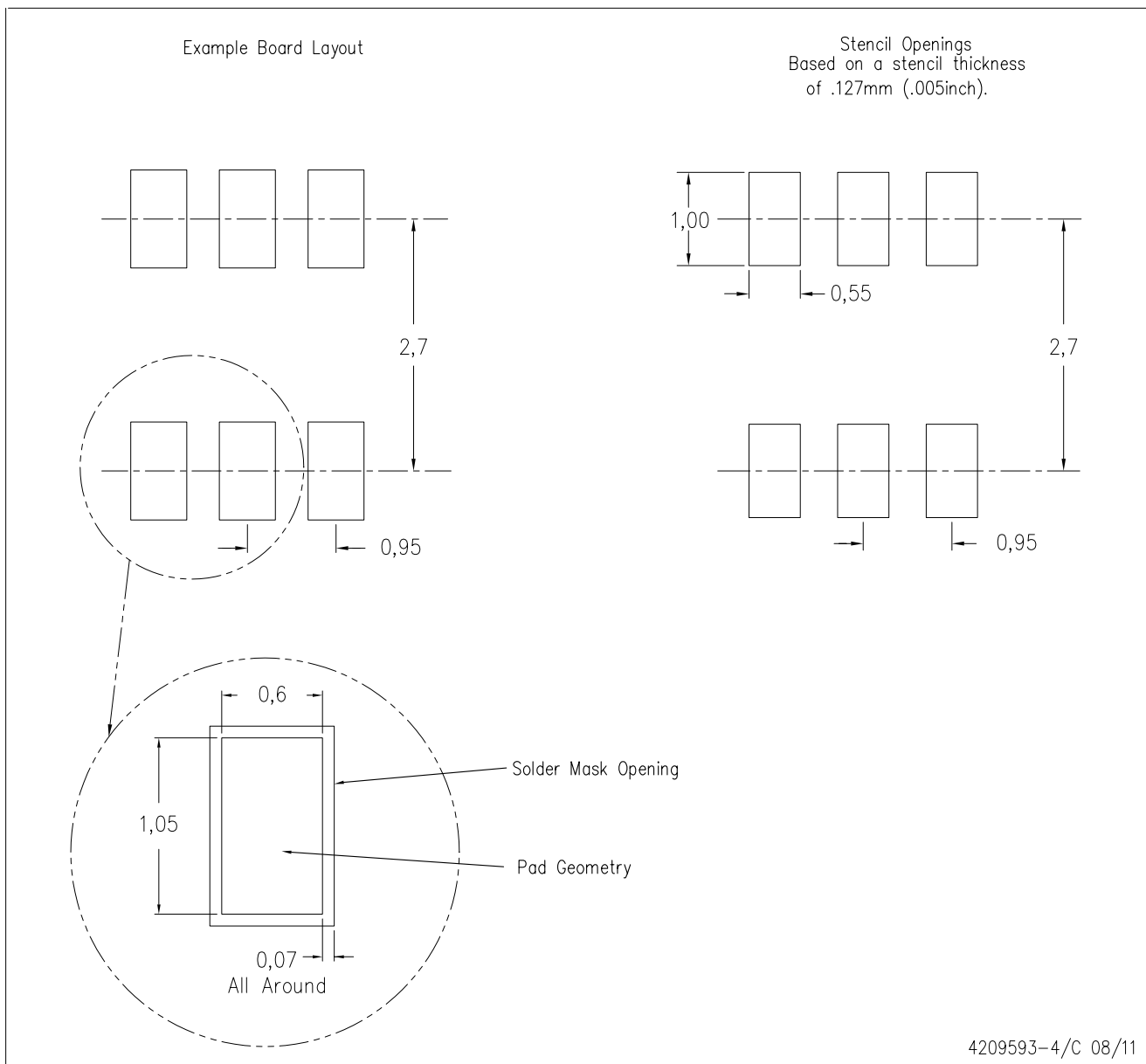
4073253-5/N 12/14

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
  - E. Falls within JEDEC MO-178 Variation AB, except minimum lead width.



DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

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| RFID                         | <a href="http://www.ti-rfid.com">www.ti-rfid.com</a>                                 |
| OMAP Applications Processors | <a href="http://www.ti.com/omap">www.ti.com/omap</a>                                 |
| Wireless Connectivity        | <a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a> |

### Applications

|                               |                                                                                          |
|-------------------------------|------------------------------------------------------------------------------------------|
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| Consumer Electronics          | <a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>                   |
| Energy and Lighting           | <a href="http://www.ti.com/energy">www.ti.com/energy</a>                                 |
| Industrial                    | <a href="http://www.ti.com/industrial">www.ti.com/industrial</a>                         |
| Medical                       | <a href="http://www.ti.com/medical">www.ti.com/medical</a>                               |
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